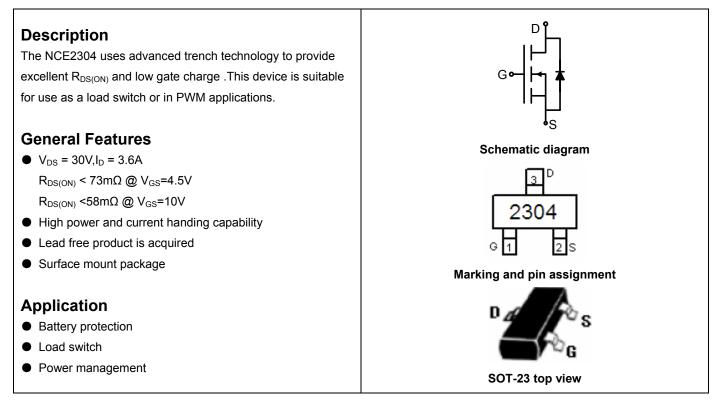




# NCE N-Channel Enhancement Mode Power MOSFET



### Package Marking and Ordering Information

U	0	0			
Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
2304	NCE2304	SOT-23	Ø180mm	8 mm	3000 units

### Absolute Maximum Ratings (T<sub>A</sub>=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	30	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	ID	3.6	A
Drain Current-Pulsed (Note 1)	I <sub>DM</sub>	15	A
Maximum Power Dissipation	PD	1.7	W
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 150	°C

### **Thermal Characteristic**

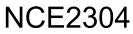
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ extsf{ heta}JA}$	73.5	°C <b>/W</b>
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### Electrical Characteristics (T<sub>A</sub>=25<sup>°</sup>C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	$BV_{DSS}$	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	30	33	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =30V, $V_{GS}$ =0V	-	-	1	μA



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Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}$ =±20V, $V_{DS}$ =0V	-	-	±100	nA
On Characteristics (Note 3)	·					
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250µA	1.2	1.5	2.2	V
Drain Source On State Registeres	Rds(on)	V <sub>GS</sub> =4.5V, I <sub>D</sub> =3.1A	-	58	73	mΩ
Drain-Source On-State Resistance		V <sub>GS</sub> =10V, I <sub>D</sub> =3.6A	-	40	58	mΩ
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =5V,I <sub>D</sub> =3.6A	-	11	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>	(-1E)()(-0)(	-	230	-	PF
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =15V,V <sub>GS</sub> =0V, F=1.0MHz	-	40	-	PF
Reverse Transfer Capacitance	Crss		-	17	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	10	-	nS
Turn-on Rise Time	tr	V <sub>DD</sub> =10V,I <sub>D</sub> =3.6A	-	50	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =4.5V, $R_{GEN}$ =6 $\Omega$	-	10	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	20	-	nS
Total Gate Charge	Qg		-	4.0	-	nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =15V,I <sub>D</sub> =3.6A, V <sub>GS</sub> =10V	-	0.75	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> -10V	-	0.65	-	nC
Drain-Source Diode Characteristics	·					
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =2.7A	-	0.8	1.2	V
Diode Forward Current (Note 2)	Is		-	-	1.6	А

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.
- **3.** Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production



NCE2304



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## Typical Electrical and Thermal Characteristics

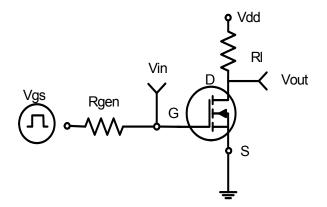
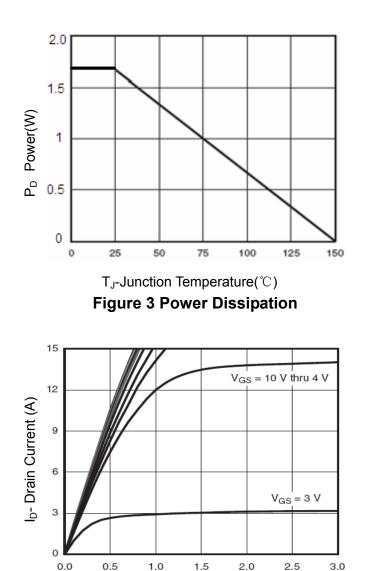
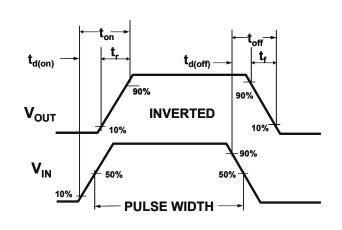


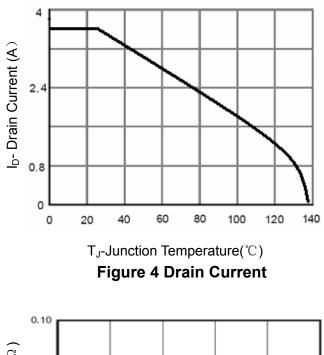
Figure 1:Switching Test Circuit

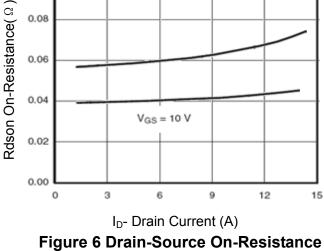












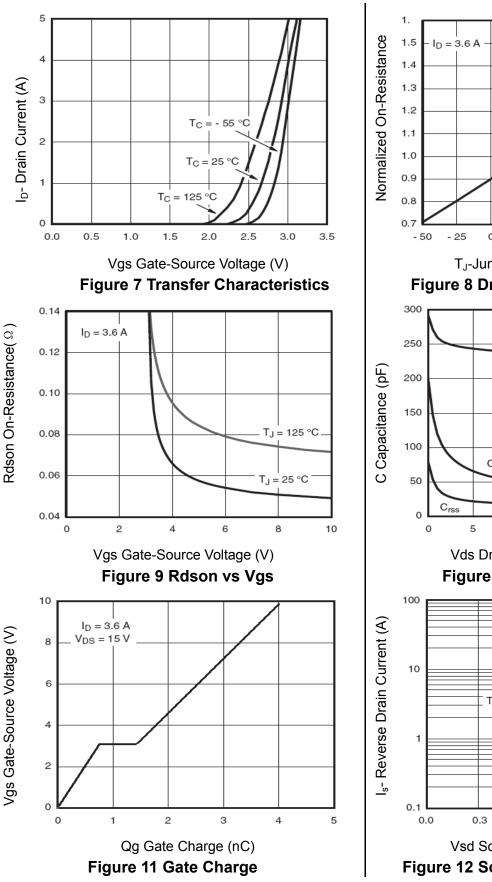


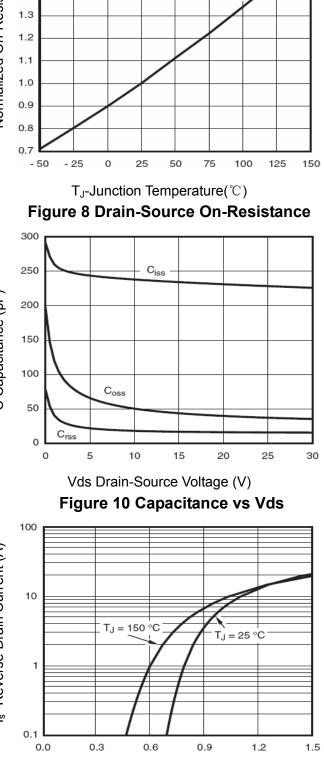
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**Pb Free Product** 

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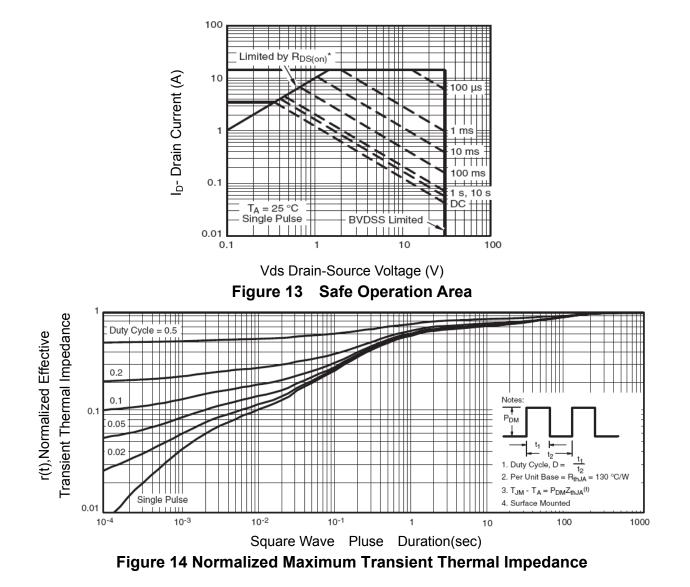
V<sub>GS</sub> = 10 V







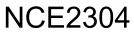




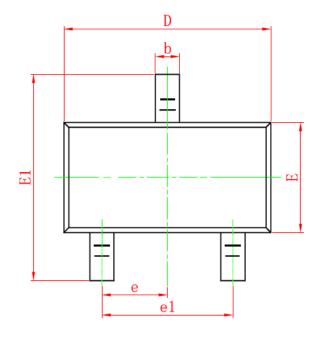


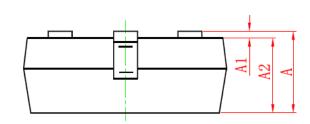
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# **SOT-23 Package Information**





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Symbol	Dimensions in Millimeters			
	MIN.	MAX.		
Α	0.900	1.150		
A1	0.000	0.100		
A2	0.900	1.050		
b	0.300	0.500		
С	0.080	0.150		
D	2.800	3.000		
Е	1.200	1.400		
E1	2.250	2.550		
е	0.950TYP			
e1	1.800	2.000		
L	0.550REF			
L1	0.300	0.500		
θ	<b>0°</b>	8°		

### Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.







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